

Specifications

Frequency Range 100 kHz to 2160 MHz (SMGU)
 100 kHz to 4320 MHz (SMHU)
 Underrange (specs not binding) down to 1 kHz

Frequency bands
 If the step width is small, there is hysteresis on band switchover

Frequency range (nominal) (MHz)	Frequency range (end points with hysteresis) (MHz)
2160 to 4320	2159.000001 to 4320
1000 to 2160	1000 to 2160
500 to 1000	500 to 1000.249999
250 to 500	250 to 500.124999
125 to 250	125 to 250.062499
62.5 to 125	62.5 to 125.031249
31.25 to 62.5	31.25 to 62.515624
15.625 to 31.25	15.625 to 31.257812
0.1 to 15.625	0.1 to 15.749999
0.1 to 125	0.1 to 125.499999

Resolution 0.1 Hz
 Stability same as reference frequency
 Setting time < 10 ms, < 1 ms in fast mode
 (to within $< 1 \times 10^{-9} \times f_c$ for $f > 15.625$ MHz,
 < 150 Hz for $f < 15.625$ MHz,
 with the special function "heterodyne band 125 MHz"
 to within < 650 Hz for $f < 125$ MHz)

Phase offset set in 1° steps

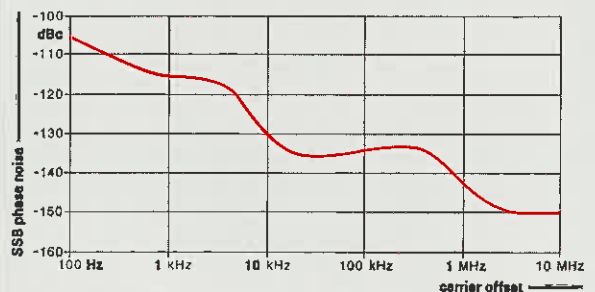
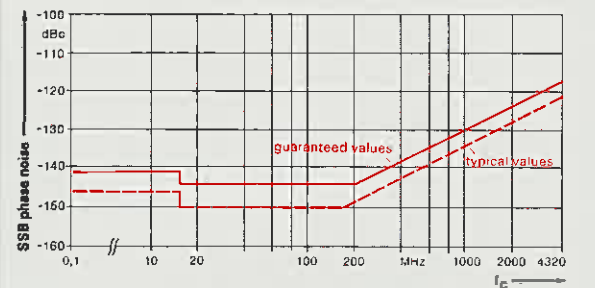
Reference frequency
 Aging $< 1 \times 10^{-9}$ /day after 30 d operation
 Temperature variation $< 2 \times 10^{-9}/^{\circ}\text{C}$
 Output (V_{rms}) 0.5 V into 50 Ω
 Frequency 5 or 10 MHz, selectable by means of special function
 Input (V_{rms}) 0.1 to 2 V
 Frequency 5 or 10 MHz $\pm 3 \times 10^{-8}$

Spectral purity
Spurious signal
 Harmonics < -30 dBc
 Subharmonics
 f < 2160 MHz none
 f > 2160 MHz < -60 dBc¹⁾
 Nonharmonics
 > 10 kHz from carrier¹⁾
 f ≤ 1000 MHz < -100 dBc¹⁾
 f > 1000 MHz < -94 dBc
 f > 2160 MHz < -88 dBc

Wideband noise for CW¹⁾
 (offset from carrier > 2 MHz;
 > 5 MHz for f > 2.16 GHz,
 1 Hz bandwidth) typ. < -145 dBc

Single-sideband phase noise 20 kHz from carrier at a bandwidth of 1 Hz (FM/ϕM deviation < 2% of maximum deviation)²⁾

Carrier (MHz)	15.6	125	250	500	1000	2000	4000
Phase noise (dBc)	< -141	< -144	< -142	< -136	< -130	< -124	< -118



Typical single-sideband phase noise at 1000 MHz

Residual FM, rms (FM/ϕM deviation < 2% of maximum deviation)

Frequency range (MHz)	Weighting bandwidth	
	0.3 to 3 kHz (CCITT) (Hz)	0.03 to 20 kHz (Hz)
0.1 to 500	< 0.5	< 1
500 to 1000	< 1	< 2
1000 to 2160	< 2	< 4
2160 to 4320	< 4	< 8

Residual AM, rms (0.3 to 3 kHz) < 0.01 %

Level
 Range -140 to +13 dBm
 Overrange not to specifications to 16 dBm (SMGU)
 to 19 dBm (SMHU)

Resolution 0.1 dB
 Total error for levels > -127 dBm¹⁾
 f ≤ 2160 MHz < ±1.5 dB
 f > 2160 MHz < ±2.5 dB

Flatness at 0 dBm¹⁾
 f ≤ 2160 MHz < 1 dB
 f > 2160 MHz < 1.5 dB

Output impedance 50 Ω
VSWR < 1.5 for levels ≤ 0 dBm (SMGU)¹⁾
 < 1.8 for levels > 0 dBm (SMGU)²⁾
 < 1.8 for f ≤ 3000 MHz (SMHU)
 < 2.5 for f > 3000 MHz (SMHU)

Setting time < 25 ms (< 10 ms for transient-free level settings)

Transient-free level settings 0 to -20 dB, from any level

Reverse power protection
 (protects the set from externally applied RF power (50-Ω source) and DC voltages)
 Max. RF power 50 W (SMGU)
 30 W (SMHU)
 Max. DC 35 V

Modulation generator
AF synthesizer
 Frequency range
 Sine 1 Hz to 100 kHz
 Sawtooth, squarewave 1 Hz to 2 kHz
 Resolution 1 Hz
 Display 4 digits, floating point
 Frequency error < 4 × 10⁻⁶
 Output level (V_r)
 AF INT connector 0.2 mV to 2 V
 Resolution up to 200 mV 0.2 mV
 Resolution above 200 mV 2 mV
 Level error at 1 kHz < 1% + 0.5 mV
 Frequency response flatness
 up to 20 kHz < ±2.5 %
 up to 100 kHz < ±3.5 %
 Distortion (level > 0.5 V) < 0.1 %
 Setting time for phase-continuous frequency changes < 5 ms
 AF fixed-frequency generator 409.6 Hz, 1024 Hz

Amplitude modulation
 Operating modes INT, EXT AC, EXT DC, two tones
 Modulation depth 0 to 100 %
 (modulation depths that meet the AM specifications decrease linearly between 7 and 13 dBm; a status message is output if the modulation depth is too great.)
 Resolution 0.1 %
 Setting error at 1 kHz and m < 80 %¹⁾
 f < 2160 MHz < (4% of reading + 1%)
 f > 2160 MHz < (6% of reading + 1%)
AM distortion at 1 kHz¹⁾
 and m = 80 % < 2 %
Modulation frequency (3 dB bandwidth)
 AM EXT AC (DC) 10 Hz (DC) to 50 kHz
 AM INT 1 Hz to 50 kHz
Modulation frequency response¹⁾
 10 Hz (DC) to 20 kHz < 1 dB
 Incidental ϕM, AM (30 %), f_{mod} = 1 kHz
 f < 2000 MHz < 0.2 rad
 f > 2000 MHz < 0.4 rad
Modulation input AM EXT
 Input impedance 100 kΩ, link selectable to 600 Ω
 Input voltage for the set modulation depth (V_p) 1 V (high/low display at ±3%)

AM square (AM-SQU)
 Dynamic range¹⁾ typ. 30 dB
 Rise/fall time typ. 2 μs
 Modulation signal (AM EXT) logic signal (low < 1 V/high > 3.5 V),
 polarity selectable via special function

Frequency modulation
 Operating modes INT, EXT AC, EXT DC, two tones, preemphasis

Carrier (MHz)	Max. dev. (kHz)	Max. dev. (kHz) with preemphasis
2160 to 4320	3200	800
1000 to 2160	1600	400
500 to 1000	800	200
250 to 500	400	100
125 to 250	200	50
62.5 to 125	100	25
31.25 to 62.5	50	12.5
15.625 to 31.25	25	6.25
0.1 to 15.625	200	50
0.1 to 125 ^{*)}	800	200

^{*)} With the "125 MHz heterodyne band"

Resolution < 1 %, min. 10 Hz
Setting error at
 f_{mod} = 1 kHz < 3% of reading + 20 Hz
 with preemphasis < 5% of reading + 20 Hz
FM distortion at 1 kHz
 and half max. deviation < 0.2% (< 1% with preemphasis)
Modulation frequency
 FM INT 10 Hz to 100 kHz
 FM EXT AC (DC) 10 Hz (DC) to 100 kHz,
 10 Hz (DC) to 1 MHz (with deviation < 10% of maximum deviation)

Modulation frequency response
 20 Hz to 100 kHz < 0.5 dB
 Preemphasis 50 μs, 75 μs
 Incidental AM at f_{mod} = 1 kHz,
 deviation = 40 kHz (f > 1 MHz) < 0.1 %
 Carrier frequency deviation at FM
 f > 15.625 MHz < 1 × 10⁻⁷ × f_c + 1% of deviation
 f < 15.625 MHz < 15 Hz + 1% of deviation
 With the "125 MHz heterodyne band" special function for
 f < 125 MHz < 65 Hz + 1% of deviation
Modulation input FM/ϕM EXT
 Input impedance 100 kΩ, link selectable to 600 Ω
 Input voltage for deviation set (V_p) 1 V (high/low display at ±3%)

FSK modulation
 The deviation is the same as for FM.
Frequency accuracy same as for FM AC + 4% of deviation
 Rise/fall time 10 μs
 Modulation signal (FM/ϕM EXT) logic signal (low < 1 V/high > 3.5 V),
 polarity selectable with special function

Phase modulation
 Operating modes INT, EXT AC, dual tone

ϕM deviation

Carrier (MHz)	Max. dev. (rad)
2160 to 4320	320
1000 to 2160	160
500 to 1000	80
250 to 500	40
125 to 250	20
62.5 to 125	10
31.25 to 62.5	5
15.625 to 31.25	2.5
0.1 to 15.625	20
0.1 to 125 ^{*)}	80

^{*)} With the "heterodyne band 125 MHz" special function

Resolution < 1 %, min. 0.001 rad
Setting error at f_{mod} = 1 kHz < 5% of reading + 0.01 rad
ϕM distortion at f = 1 kHz
 and half max. deviation < 0.5 %
Modulation frequency 10 Hz to 10 kHz
Modulation frequency response
 10 Hz to 10 kHz < 1 dB
 Carrier frequency deviation same as for FM
 (FM dev. = ϕM dev. × 10 kHz)
Modulation input FM/ϕM EXT
 Input impedance 100 kΩ, link selectable 600 Ω
 Input voltage for the deviation set (V_p) 1 V (high/low display at ±3%)

Pulse modulation
 Operating mode external
 On/off ratio > 80 dB
 Rise/fall time < 20 ns (f > 125 MHz)
 Modulation signal HCT signal, selectable polarity by means of a special function

Simultaneous modulation AM + FM, AM + ϕM, FM + Pulse,
 ϕM + Pulse

Sweep
 Operating modes automatic, single shot or manual

	RF sweep	AF sweep	RF level sweep	Memory sweep
Sweep range	user select.	user select.	0.1 to 20 dB	user select.
Step width (lin)	user select.	user select.	—	1
Step width (log)	0.01 to 50%	0.01 to 50%	0.1 to 20 dB	—
Time for step	10 ms to 1 s	10 ms to 1 s	10 ms to 1 s	50 ms to 60 s 1 ms to 60 s ^{*)}
Marker	user select.	user select.	user select.	—

^{*)} In fast mode

X output 0 to 10 V
Z output 0/5 V logic signal, polarity, selection via special function

Remote control
 System IEC 625-1 (IEEE 488)
 Connector type Amphenol 24-contact
 Remote controllable functions all, except those of spinwheel and power switch set via the keypad (0 to 30)
 IEC-bus address SH1, AH1, T6, L4, SR1, RL1, PPO
 Interface functions DC1, DT1, C0

General data
 Rated temperature range 0 to 50 °C
 Storage temperature range -40 to +75 °C
 RF leakage to VDE 0871 and MIL STD 461 B (Method CE 03 and RE 02), radiated and conducted interference; also meets VDE 0875 (RFI class K)

Mechanical shock Shock tested to DIN 40046, part 7 (30 g, 11 ms) and vibration tested to DIN 40046, part 8 (5 to 55 Hz, 2 g); corresponds to IEC Publications 68-2-27 and 68-2-6
 100/120/220/240 V ± 10 %
 47 to 63 Hz (max. 270 VA)
 safety class I to VDE 0411 (IEC 348)

Power supply 435 mm × 192 mm × 460 mm
 Weight 25 kg

Supplementary data for model SMGU 55
 Level range -140 to +16 dBm
 Overage not to specifications to +19 dBm
 Frequency response at 0 dBm¹⁾
 9 kHz ≤ f ≤ 2160 MHz < 1 dB
 Harmonic spurious signals
 for levels ≤ 13 dBm < -30 dBc
 for levels ≤ 16 dBm < -25 dBc

Supplementary data for models SMGU 56 and SMHU 56
 Number of memory locations 4800
 Parallel interface (fast hop bus) 13 address lines (A₃ to A₁₂) and DATA VALID

Ordering information

Order designations	▶ Signal Generator SMGU
Model 52 (standard model)	819.0010.52
Model 55 with extended level range	819.0010.55
Model 56 with extended memory capacity and parallel interface	819.0010.56
Model 52 (standard model)	▶ Signal Generator SMHU
Model 56 with extended memory capacity and parallel interface	835.8011.52
Supplied accessories	835.8011.56 power cable

Recommended extras
 Rear-panel connectors for RF and AF SMGU-Z9 820.4415.02
 19" Rack Adapter ZZA-94 396.4905.00
 Service Kit SMGU-Z2 820.4515.02
 Service Manual for SMGU 820.4150.02
 for SMHU 820.4180.02

¹⁾ does not apply to special function "transient-free level settings".
²⁾ does not apply to special function "125 MHz heterodyne band".
³⁾ does not apply to special function "AGC off" and to pulse modulation.